

2 N 5266	Isi,Mot	P-FET	Uni, 60V, Idss>0,8mA, Up<3V	5n	TO-72	-	
2 N 5267	Isi,Mot	P-FET	Uni, 60V, Idss>1,5mA, Up<6V	5n	TO-72	2N5463...64	
2 N 5268	Isi,Mot	P-FET	Uni, 60V, Idss>2,5mA, Up<6V	5n	TO-72	2N5463...64	
2 N 5269	Isi,Mot	P-FET	Uni, 60V, Idss>4mA, Up<8V	5n	TO-72	2N5465	
2 N 5270	Isi,Mot	P-FET	Uni, 60V, Idss>7mA, Up<8V	5n	TO-72	-	
2 N 5271	Mot,Sca	Si-N	S, Avalanche, 280V, -5/A, 0,6W	2a	TO-39	-	
2 N 5272	Sty	Si-N	S, 40/20V, 0,2A, 0,36W, >500MHz, <23/28ns	2a	TO-18	BSS 10...11, BSX 19...20, 2N2368...69(A),++	
2 N 5273	Tix	Triac	200V, 25A=(Tc=60°), Igt/Ih<150/<100mA	211	TO-48	2N5806, BTX 94/200	
2 N 5274		Triac	=2N5273: 400V	211	TO-48	2N5807, BTX 94/400	
2 N 5275		Triac	=2N5273: 600V	211	TO-48	2N5809, BTX 94/600	
2 N 5276	Tix	Si-N	S, RadH, 25/15V, 0,36W, >600MHz, hFE=30...90	2a	TO-18	-	
2 N 5277	Six,Tix	N-FET	S, 150V, Idss>2,5mA, Up<7V	2b	TO-5	-	
2 N 5278	Six,Tix	N-FET	S, 150V, Idss>10mA, Up<10V	2b	TO-5	-	
2 N 5279	Sca,Ssi,Stc	Si-N	S,Vid, 400/300V, 1A, 1W, >15MHz, hFE=40...160	2a	TO-5	BFQ 40, BSS 49, 2N3439	
2 N 5280		Si-N	=2N5279: 15W	43m	=TO-37	(BD 410, BUW 40(A,B), TIP 49...50,++) ⁴	
2 N 5281	Sca,Ssi,Stc	Si-P	S,Vid, 175/150V, 1A, 2W(Tc=100°), >20MHz, hFE>20	2a	TO-5	BFT 19(A,B), BFT 28A...C, 2N5415...16, ++	
2 N 5282		Si-P	=2N5281: 325/300V	2a	TO-5	BFT 19B, 2N5416, MJ 5416	
2 N 5284	USA	Si-N	S P, 120/100V, 5A, 50W(Tc=50°), >60MHz, hFE=30...90	49a	TO-59	-	
2 N 5285		Si-N	=2N5284: >70MHz, hFE=70...200	{2N5286...87	49a	TO-59	-
2 N 5286	USA	Si-P	S P, 120/100V, 5A, 50W(Tc=50°), >60MHz, hFE=30...90	49a	TO-59	-	
2 N 5287		Si-P	=2N5286: >70MHz, hFE=70...200	{2N5284...85	49a	TO-59	-
2 N 5288	USA	Si-N	S P, 120/100V, 10A, 100W(Tc=50°), >30MHz, hFE>30	49a	TO-61	2N5542	
2 N 5289		Si-N	=2N5288: >40MHz, hFE=70...200	{2N5290...91	49a	TO-61	2N5542
2 N 5290	USA	Si-P	S P, 120/100V, 10A, 100W(Tc=50°), >30MHz, hFE>30	49a	TO-61	-	
2 N 5291		Si-P	=2N5290: >40MHz, hFE=70...200	{2N5288...89	49a	TO-61	-
2 N 5292	Fch,Spe,Sty	Si-P	S, RadH, 12/12V, 0,1A, 0,36W, >800MHz, hFE=40...100	2a	TO-18	-	
2 N 5293	USA,Mic,Nsc	Si-N	LFS P, 80/70V, 4A, 36W, >0,8MHz, <5/15µs, hFE=30...120	17j	TO-220AA	BD 243 C 17j	BD 243B, BD 537, BD 539B, BD 951, ++
2 N 5294	Rca,Tho,Tos	Si-N	=2N5293:	17j	TO-220AB	BD 243 C 17j	BD 243B, BD 537, BD 539B, BD 951, ++
2 N 5295		Si-N	=2N5293: 60/40V	17j	TO-220AA	BD 243 C 17j	BD 243A, BD 535, BD 539A, BD 949, ++
2 N 5296		Si-N	=2N5295:	17j	TO-220AB	BD 243 C 17j	BD 243A, BD 535, BD 539A, BD 949, ++
2 N 5297		Si-N	=2N5293: 80/60, hFE=20...80	17j	TO-220AA	BD 243 C 17j	BD 243B, BD 537, BD 539B, BD 951, ++
2 N 5298		Si-N	=2N5297:	17j	TO-220AB	BD 243 C 17j	BD 243B, BD 537, BD 539B, BD 951, ++
2 N 5301	USA,Mot,Rca	Si-N	LFS P, 40/40V, 30/50A, 200W, >2MHz, <1/3µs, hFE=15...60	23a	TO-3	BDY 29, MJ 802, 2N3771, 2SD630, 2SD797	
2 N 5302	Sgs,Tix,Tos	Si-N	=2N5301: 60/60V	{2N4398	TO-3	BDY 29, MJ 802, 2SD797	
2 N 5303		Si-N	=2N5301: 80/80V	{2N4399 23a	TO-3	BDY 29, MJ 802, 2SD797	
2 N 5304	Mot,Stc	Si-N	S P, RadH, 50/40V, 10A, 25W(Tc=125°), >100MHz	49m	TO-61	-	
2 N 5305	USA,Mic,Nsc	Si-N-Darl	LF Inp, 25/25V, 0,3A, 0,4W, hFE=2k...20k, >60MHz	7c	TO-98	BC 517, BC 617, MPS-A13...14, 2SD892, ++	
2 N 5306		Si-N-Darl	=2N5305: hFE=7k...70k	7c	TO-98	BC 517, BC 617, MPS-A13...14, 2SD892, ++	
2 N 5306 A		Si-N-Darl	=2N5305: In, hFE=7k...70k, Ur=195nV(1kHz)	7c	TO-98	-	
2 N 5307		Si-N-Darl	=2N5305: 40/40V	7c	TO-98	BC 517, BC 617, MPS-A25...29, 2SD892A, ++	
2 N 5308		Si-N-Darl	=2N5305: 40/40V, hFE=7k...70k	7c	TO-98	BC 517, BC 617, MPS-A25...29, 2SD892A, ++	
2 N 5308 A		Si-N-Darl	=2N5305: In, 40/40V, hFE=7k...70k, Ur=195nV(1kHz)	7c	TO-98	-	
2 N 5309	Gen,Sem,Spr	Si-N	LF, 70/50V, 0,1A, 0,36W, hFE=60...120	7c	TO-98	BC 174, BC 182, BC 190, BC 546, ++	
2 N 5310		Si-N	=2N5309: hFE=100...300	7c	TO-98	BC 174, BC 182, BC 190, BC 546, ++	
2 N 5311		Si-N	=2N5309: hFE=250...500	7c	TO-98	BC 174, BC 182, BC 190, BC 546, ++	
2 N 5312	USA	Si-P	S P, 80/80V, 10A, 50W(Tc=100°), >30MHz, <0,5/1,5µs	49m	TO-61	2N5290...91	
2 N 5313	USA	Si-N	S P, 80/80V, 10A, 50W(Tc=100°), >30MHz, <0,5/1,5µs	49m	TO-61	2N5288...89	
2 N 5314		Si-P	=2N5312: 100/100V	49m	TO-61	2N5290...91	
2 N 5315		Si-N	=2N5313: 100/100V	49m	TO-61	2N5288...89	
2 N 5316		Si-P	=2N5312: Iso	49a	TO-61	2N5290...91	
2 N 5317		Si-N	=2N5313: Iso	49a	TO-61	2N5288...89	
2 N 5318		Si-P	=2N5312: Iso, 100/100V	49a	TO-61	2N5290...91	
2 N 5319		Si-N	=2N5313: Iso, 100/100V	49a	TO-61	2N5288...89	
2 N 5320	USA,Rca,Sgs	Si-N	LFS, 100/75V, 2A, 10W(Tc=25°), >50MHz, <80/800ns, hFE=30...130	2a	TO-5	(2SC4135) ⁴ 30j	BSS 15, BSV 84, 2N4239, 2SD854
2 N 5321	Mot,Tix	Si-N	=2N5320: 75/50, hFE=40...250	{2N5322	TO-5	(2SC4135) ⁴ 30j	BSS 15, BSV 84, 2N4238...39, 2SD854
2 N 5322	USA,Rca,Sgs	Si-P	LFS, 100/75V, 2A, 10W(Tc=25°), >50MHz, <100/1000ns, hFE=30...130	2a	TO-5	(2SA1593) ⁴ 30j	BSS 17
2 N 5323	Mot,Tix	Si-P	=2N5322: 75/50V, hFE=40...250	{2N5321	TO-5	(2SA1593) ⁴ 30j	BSS 17...18, 2N4236
2 N 5324	Gpd,Mot,Sem	Ge-P	TV-HA, 250/150V, 10A, 56W, >2MHz, <15/17µs	23a	TO-3	AU 113, AU 213	
2 N 5325		Ge-P	=2N5324: 325/200V	23a	TO-3	AU 106, AU 109, AU 111...112	
2 N 5326	USA,Tix	Si-N	S P, 100/80V, 5A, 20W(Tc=100°), >80MHz, <150/400ns	49a	TO-59	2N5002, 2N5004, 2N5284...85	
2 N 5327	USA,Tix	Si-N	S, 100/80V, 10A, 5W(Tc=100°), >100MHz, <200/900ns	2a	TO-5	BUY 82	
2 N 5328	USA,Tix	Si-N	S P, 100/80V, 10A, 30W(Tc=100°), >100MHz, <200/900ns	49a	TO-59	2N5348...49	
2 N 5329	USA,Tix	Si-N	S P, 150/90V, 20A, 65W(Tc=100°), >80MHz, <350/1100ns	49a	TO-61	-	
2 N 5330	USA,Tix	Si-N	S P, 150/90V, 30A, 80W(Tc=100°), >80MHz, <350/1100ns	49a	TO-61	-	
2 N 5331	USA,Tix	Si-N	S P, 150/90V, 30A, 100W(Tc=100°), >80MHz, <350/1100ns	49a	TO-63	2N2825	
2 N 5332	Mot,Tix	Si-P	S, RadH, 20/12V, 0,1A, 0,36W, >800MHz	2a	TO-52	-	
2 N 5333	USA,Tix	Si-P	LFS, 100/80V, 2/5A, 1W, >30MHz, 150/450ns	2a	TO-5	BSS 17, 2N5322	
2 N 5334	USA,Mot	Si-N	LFS, 60/60V, 3A, 6W(Tc=25°), >60MHz, <100/1050ns	2a	TO-39	BSX 62...64, 2N4237...39, 2SC2214	
2 N 5335		Si-N	=2N5334: 80/80V	2a	TO-39	BSX 63...64, 2N4238...39, 2SC2214	
2 N 5336	USA,Mot,Nsc	Si-N	LFS, 80/80V, 5/7A, 1W, 6W(Tc=25°), <200/2200ns, >30MHz, hFE=30...120	2a	TO-39	BFT 32...34, BUX 34, BUY 80, 2N4895...97	
2 N 5337	Sgs,Tix	Si-N	=2N5336: hFE=60...240	{2N6190	TO-39	BFT 32...34, BUX 34, BUY 80, 2N4895...97	
2 N 5338		Si-N	=2N5336: 100/100V	{2N6191 2a	TO-39	BFT 33...34, BUX 34, BUY 80, 2N4895...97	
2 N 5339		Si-N	=2N5336: 100/100V, hFE=60...240	2a	TO-39	BFT 33...34, BUX 34, BUY 80, 2N4895...97	
2 N 5344	Mot,Stc	Si-P	LFS P, 250/250V, 1A, 40W, >60MHz	22a	TO-66	BUX 66A...C, 2N6421, 2SA1009(A), 2SA1397	
2 N 5345		Si-P	=2N5344: 300/300V	22a	TO-66	BUX 66A...C, 2N6421, 2SA1009(A), 2SA1397	
2 N 5346	USA,Mot	Si-N	=2N5336: 7A, 60W	{2N6186	TO-59	-	
2 N 5347	USA,Mot	Si-N	=2N5337: 7A, 60W	{2N6187	TO-59	-	
2 N 5348	USA,Mot	Si-N	=2N5338: 7A, 60W	{2N6188	TO-59	-	
2 N 5349	USA,Mot	Si-N	=2N5339: 7A, 60W	{2N6189	TO-59	-	
2 N 5350		Si-N	S P, 125/100V, 350W, >10MHz	-	-	-	
2 N 5351		Si-N	S-L, 180/150V, 350W, >10MHz	-	-	-	
2 N 5354	USA,Mic,Nsc	Si-P	Uni, 25/25V, 0,3A, 0,36W, 250MHz, hFE=40...120	7c	TO-98	BC 327...328, BC 636, BC 638, BC 640, ++	
2 N 5355		Si-P	=2N5354: hFE=100...300	7c	TO-98	BC 327...328, BC 636, BC 638, BC 640, ++	
2 N 5356		Si-P	=2N5354: hFE=250...500	7c	TO-98	BC 327...328, BC 636, BC 638, BC 640, ++	
2 N 5357	Mot,Mic,Stc	Si-P	S P, 300/300V, 3A, 30W(Tc=75°), >50MHz	43m	TO-37	(2SA1009(A), 2SA1236, 2SA1397) ⁴	
2 N 5358	USA,Mot,Tix	N-FET	Uni, In, 40V, Idss>0,5mA, Up<3V	5m	TO-72	2N4339, 2SK83, 2SK193, 2SK195	
2 N 5359	USA,Mot,Tix	N-FET	Uni, In, 40V, Idss>0,8mA, Up<4V	5m	TO-72	-	
2 N 5360	USA,Mot,Tix	N-FET	Uni, In, 40V, Idss>1,5mA, Up<4V	5m	TO-72	2N5246	